NSN 5961-01-369-6482

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-369-6482 **Inclosure Material:** Metal **Overall Length:** 0.900 inches **Overall Height:** 0.215 inches **Overall Width:** 0.800 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 collector supply voltage and 50.0 collector supply voltage **Current Rating Per Characteristic:** 7.00 amperes all primaries **Power Rating Per Characteristic:** 50.0 watts forward power dissipation, dc universal **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No